

Single 3-Input Positive AND-OR Gate

Check for Samples: SN74LVC1G0832

FEATURES

- Available in the Texas Instruments NanoFree[™] Package
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Provides Down Translation to V_{CC}
- Max t_{pd} of 5 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Input Hysteresis Allows Slow Input **Transition and Better Switching Noise** Immunity at the Input (V_{hvs} = 250 mV Typ @ 3.3 V)
- Can Be Used in Three Combinations:
 - AND-OR Gate
 - AND Gate
 - OR Gate
- Ioff Supports Live Insertion, Partial-Power-**Down Mode, and Back-Drive Protection**
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION

This device is designed for 1.65-V to 5.5-V V_{CC} operation.

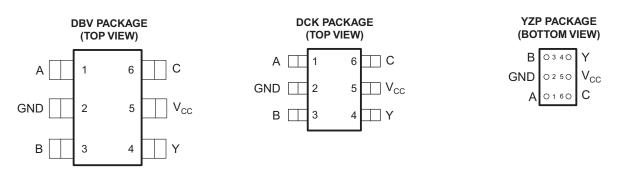
SCES606D - SEPTEMBER 2004 - REVISED DECEMBER 2013

The SN74LVC1G0832 device is a single 3-input positive AND-OR gate. It performs the Boolean function $Y = (A \bullet B) + C$ in positive logic.

By tying one input to GND or V_{CC} , the SN74LVC1G0832 device offers two more functions. When C is tied to GND, this device performs as a 2-input AND gate (Y = A • B). When A is tied to V_{CC} , the device works as a 2-input OR gate (Y = B + C). This device also works as a 2-input OR gate when B is tied to V_{CC} (Y = A + C).

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

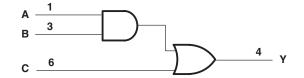


These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

	Funct	ion Ta	able ⁽¹⁾
I	NPUTS		OUTPUT
Α	В	С	Y
х	Х	Н	н
н	Н	Х	н
х	L	L	L
L	Х	L	L

(1) X = Valid H or L

Logic Diagram (Positive Logic)



Function Selection Table

LOGIC FUNCTION	FIGURE
2-Input AND Gate	Figure 1
2-Input OR Gate	Figure 2
$Y = (A \bullet B) + C$	Figure 3

www.ti.com

TRUMENTS

AS



www.ti.com Logic Configurations

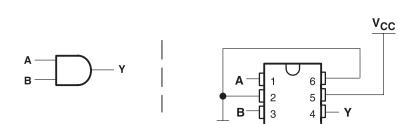


Figure 1. 2-Input AND Gate

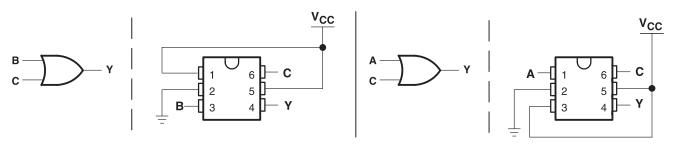
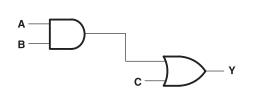


Figure 2. 2-Input OR Gate



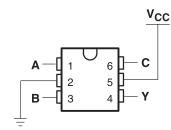


Figure 3. $Y = (A \cdot B) + C$

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Voltage range applied to Y output in the high	n-impedance or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage range applied to any output in the hi	igh or low state ⁽²⁾⁽³⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
		DBV package		215	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCK package		259	°C/W
		YZP package		123	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

www.ti.com

STRUMENTS

EXAS

4



SCES606D - SEPTEMBER 2004 - REVISED DECEMBER 2013

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V	Supply veltage	Operating	1.65	5.5	V
V _{CC}	Supply voltage	Data retention only	1.5		v
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	5.5	
V		V_{CC} = 2.3 V to 2.7 V	1.7	5.5	V
V _{IH}	High-level input voltage	$V_{CC} = 3 V$ to 3.6 V	2	5.5	v
		V_{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	5.5	
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V	0	$0.35 \times V_{CC}$	
V		V_{CC} = 2.3 V to 2.7 V	0		N
V _{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V	0		V
		V_{CC} = 4.5 V to 5.5 V	0		
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 1.65 V		-4	
		V _{CC} = 2.3 V		-8	
I _{OH}	High-level output current	<u> </u>		-16	mA
		$V_{CC} = 3 V$		-24	
		V _{CC} = 4.5 V		-32	
		V _{CC} = 1.65 V		4	
		V _{CC} = 2.3 V		8	
I _{OL}	Low-level output current	<u> </u>		16	mA
		$V_{CC} = 3 V$		24	
		V _{CC} = 4.5 V		32	
		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$		20	
Δt/Δv	Input transition rise or fall rate	V _{CC} = 3.3 V ± 0.3 V		10	ns/V
		$V_{CC} = 5 V \pm 0.5 V$		5	
T _A	Operating free-air temperature	· · · · · · · · · · · · · · · · · · ·	-40	125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

TEXAS INSTRUMENTS

www.ti.com

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER					-40°0	C to 85°C		–40°C	to 125°C		UNIT
PA	RAMETER	TEST CO	NDITIONS	V _{cc}	MIN	TYP ⁽¹⁾	MAX	MIN	MIN TYP ⁽¹⁾ MAX		
		I _{OH} = −100 μA		1.65 V to 5.5 V	V _{CC} - 0.1			V _{CC} - 0.1			
		$I_{OH} = -4 \text{ mA}$		1.65 V	1.2			1.2			
V		I _{OH} = -8 mA	V _I = 5.5 V or	2.3 V	1.9			1.9			v
V _{OH}		I _{OH} = -16 mA	GND	2.14	2.4			2.4			v
		I _{OH} = -24 mA		3 V	2.3			2.3			
		I _{OH} = -32 mA		4.5 V	3.8			3.8			
		I _{OL} = 100 μA		1.65 V to 5.5 V			0.1			0.1	
		$I_{OL} = 4 \text{ mA}$		1.65 V			0.45			0.45	
V		I _{OL} = 8 mA	V _I = 5.5 V or	2.3 V			0.3			0.3	v
V _{OL}		I _{OL} = 16 mA	GND	3 V			0.4			0.4	v
		I _{OL} = 24 mA		3 V			0.55			0.55	
		I _{OL} = 32 mA		4.5 V			0.55			0.6	
I _I	A, B, or C inputs	V _I = 5.5 V or GN	ID	0 to 5.5 V			±5			±5	μA
I _{off}		$V_{\rm I}$ or $V_{\rm O}$ = 5.5 V		0			±10			±10	μA
Icc		V _I = 5.5 V or GN	ID, I _O = 0	1.65 V to 5.5 V			10			10	μA
ΔI _{CC}		One input at V _{C0} Other inputs at V		3 V to 5.5 V			500			500	μA
Ci		$V_{I} = V_{CC}$ or GND)	3.3 V		7					pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

6

Copyright © 2004–2013, Texas Instruments Incorporated



www.ti.com

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 4)

							C1G0832 to 85°C	2			
PARAMETER	FROM (INPUT)	TO (OUTPUT)		V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		3.3 V 3 V	V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A, B, or C	Y	3.7	14	2.4	7	1.7	5	1.2	3.4	ns

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 5)

						N74LV0 -40°C t	C1G0832 to 85°C	2			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A, B, or C	Y	2.5	17.5	1.8	7.6	1.8	5.9	1.3	4	ns

Switching Characteristics

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 5)

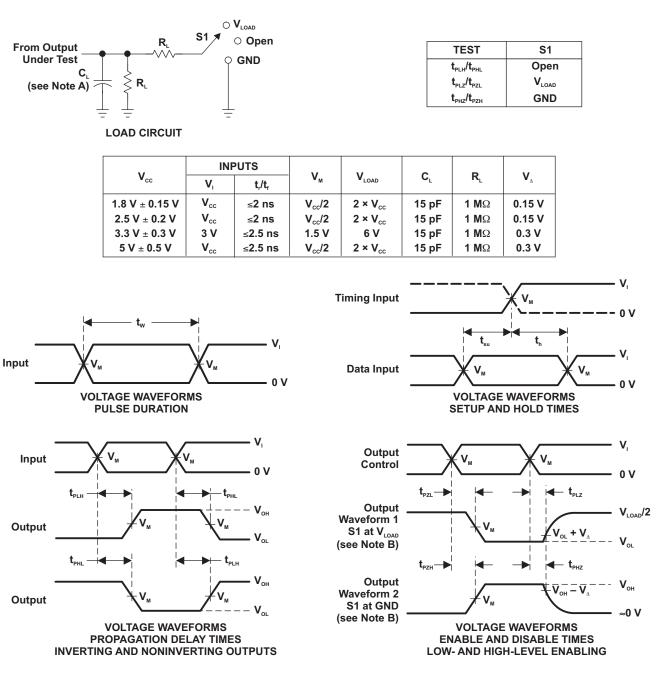
PARAMETER							C1G0832 5 125°C	!			
	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A, B, or C	Y	2.5	17.5	1.8	7.6	1.8	5.9	1.3	4.5	ns

Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	$V_{CC} = 5 V$	UNIT	
		CONDITIONS	ТҮР	TYP	TYP	TYP		
C _{pd} Power dissipation capacitance		f = 10 MHz	15	15	16	18	pF	

SCES606D-SEPTEMBER 2004-REVISED DECEMBER 2013



Parameter Measurement Information

NOTES: A. C_{L} includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. $t_{\mbox{\tiny PLH}}$ and $t_{\mbox{\tiny PHL}}$ are the same as $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

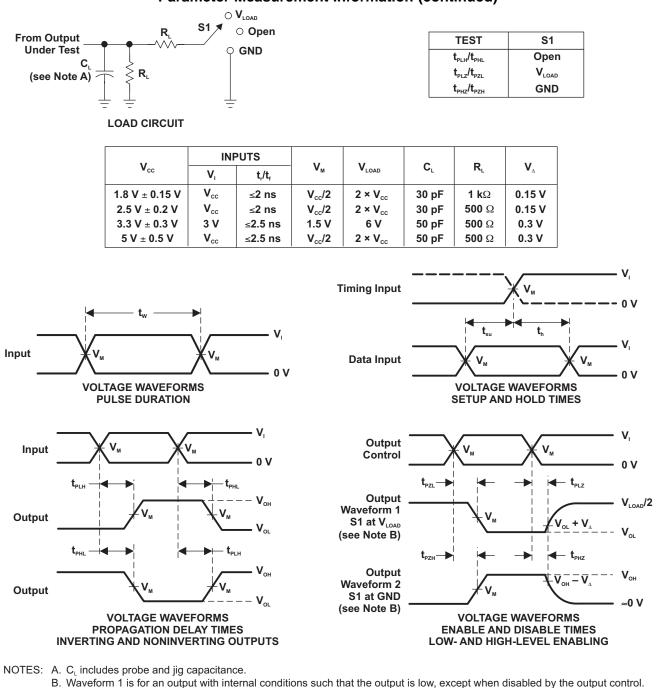


SN74LVC1G0832

www.ti.com

SCES606D-SEPTEMBER 2004-REVISED DECEMBER 2013

Parameter Measurement Information (continued)



- Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_o = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. $t_{\mbox{\tiny PZL}}$ and $t_{\mbox{\tiny PZH}}$ are the same as $t_{\mbox{\tiny en}}.$
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 5. Load Circuit and Voltage Waveforms

REVISION HISTORY

Changes from Revision C (January 2007) to Revision D

•	Updated document to new TI data sheet format.	1
•	Updated Features.	1
•	Added ESD warning.	2
•	Updated operating temperature range.	5

www.ti.com

Page



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
74LVC1G0832DCKRG4.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
SN74LVC1G0832DBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CDCR
SN74LVC1G0832DBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CDCR
SN74LVC1G0832DBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CDCR
SN74LVC1G0832DBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CDCR
SN74LVC1G0832DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(DCJ, DCR)
SN74LVC1G0832DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(DCJ, DCR)
SN74LVC1G0832DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(DCJ, DCR)
SN74LVC1G0832DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(DCJ, DCR)
SN74LVC1G0832YZPR	Active	Production	DSBGA (YZP) 6	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	DCN
SN74LVC1G0832YZPR.B	Active	Production	DSBGA (YZP) 6	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	DCN

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.



PACKAGE OPTION ADDENDUM

30-Jun-2025

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G0832DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G0832DBVT	SOT-23	DBV	6	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G0832DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G0832DCKT	SC70	DCK	6	250	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
SN74LVC1G0832DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G0832YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1



PACKAGE MATERIALS INFORMATION

4-Jan-2025



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G0832DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74LVC1G0832DBVT	SOT-23	DBV	6	250	202.0	201.0	28.0
SN74LVC1G0832DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74LVC1G0832DCKT	SC70	DCK	6	250	202.0	201.0	28.0
SN74LVC1G0832DCKT	SC70	DCK	6	250	180.0	180.0	18.0
SN74LVC1G0832YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

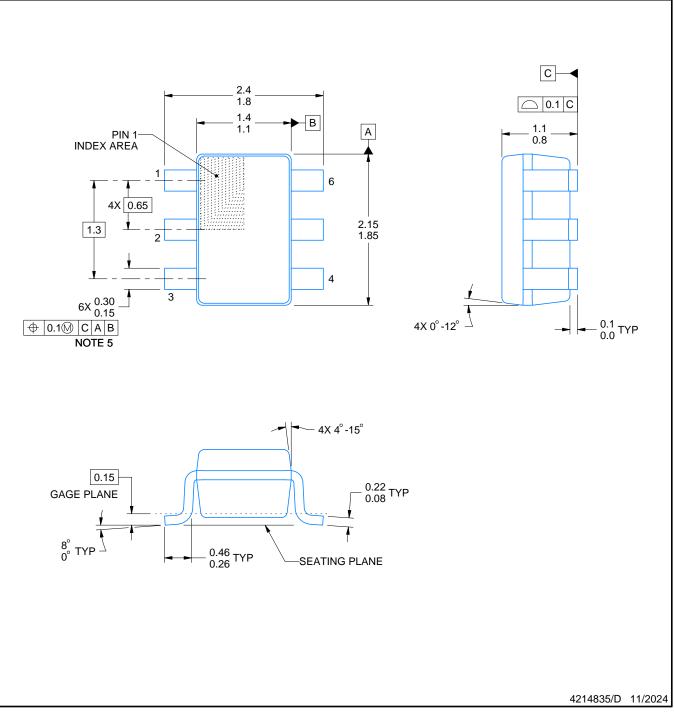
DCK0006A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing an integration of a constraint of the minimeters. Any dimensions in parentnesis are for reference only. Dimensioning and to per ASME Y14.5M.
 This drawing is subject to change without notice.
 Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 Falls within JEDEC MO-203 variation AB.



DCK0006A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

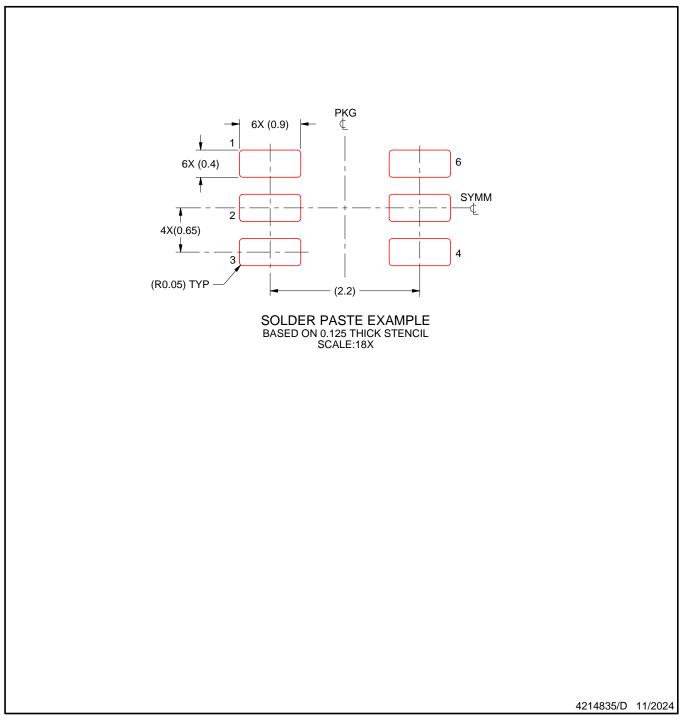


DCK0006A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Board assembly site may have different recommendations for stencil design.



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

DBV0006A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



DBV0006A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DBV0006A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



YZP0006



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

NanoFree Is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. NanoFree[™] package configuration.



YZP0006

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).



YZP0006

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated